

**Notice of References Cited**

Application/Control No.

10/580,683

Applicant(s)/Patent Under  
Reexamination  
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Examiner

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Art Unit

2828

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**U.S. PATENT DOCUMENTS**

*		Document Number Country Code-Number-Kind Code	Date MM-YYYY	Name	Classification
	A	US-			
	B	US-			
	C	US-			
	D	US-			
	E	US-			
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**FOREIGN PATENT DOCUMENTS**

*		Document Number Country Code-Number-Kind Code	Date MM-YYYY	Country	Name	Classification
	N					
	Q					
	P					
	Q					
	P					
	S					
	T					

**NON-PATENT DOCUMENTS**

*		Include as applicable: Author, Title Date, Publisher, Edition or Volume, Pertinent Pages)
	U	S. L. Chuang. Physics of Optoelectronic Devices. New York: John Wile & Sons, 1995.
*	V	Y. Sakata et al. "Al-Selective MOVPE-Grown 1.3-um Strained Multi-quantum-Well Buried-Heterostructure Laser Diodes," IEEE Journal of Quantum Electronics, Vol. 35, No. 3, March 1999
	W	
	X	

\*A copy of this reference is not being furnished with this Office action. (See MPEP § 707.05(a).)  
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